



1011LD300

300 Watts, 32 Volts

Pulsed Avionics 1030 to 1090 MHz

LDMOS FET

GENERAL DESCRIPTION

The 1011LD300 is a COMMON SOURCE N-Channel enhancement mode lateral MOSFET capable of providing 300 W_{pk} of RF power from 1030 to 1090 MHz. The device is nitride passivated and utilizes gold metallization to ensure highest MTTF. The transistor includes input prematch for broadband capability. Low thermal resistance package reduces junction temperature, extends life.

ABSOLUTE MAXIMUM RATINGS

Power Dissipation

Device Dissipation @25°C (P_d) 1590 W

Voltage and Current

Drain-Source (V_{DSS}) 75V

Gate-Source (V_{GS}) ± 20V

Temperatures

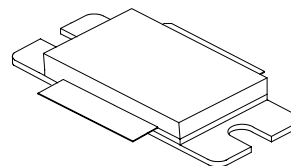
Storage Temperature -65 to +150°C

Operating Junction Temperature +200°C

CASE OUTLINE

55QM

(Common Source)



ELECTRICAL CHARACTERISTICS @ 25°C

| SYMBOL | CHARACTERISTICS | TEST CONDITIONS | MIN | TYP | MAX | UNITS |
|------------------------------|------------------------------|---|-----|-----|-----|-------|
| BV _{dss} | Drain-Source Breakdown | V _{gs} = 0V, I _d = 30mA | 75 | | | V |
| I _{dss} | Drain-Source Leakage Current | V _{ds} = 38V, V _{gs} = 0V | | | 10 | μA |
| I _{gss} | Gate-Source Leakage Current | V _{gs} = 10V, V _{ds} = 0V | | | 2 | μA |
| V _{gs(th)} | Gate Threshold Voltage | V _{ds} = 10V, I _d = 60 mA | 3 | | 6 | V |
| V _{ds(on)} | Drain-Source On Voltage | V _{gs} = 10V, I _d = 3A | | | 0.3 | V |
| g _{FS} | Forward Transconductance | V _{ds} = 10V, I _d = 3A | | 3 | | S |
| θ _{JC} ¹ | Thermal Resistance | | | | .11 | °C/W |

FUNCTIONAL CHARACTERISTICS @ 25°C, V_{ds} = 32V, I_{dq} = 750mA

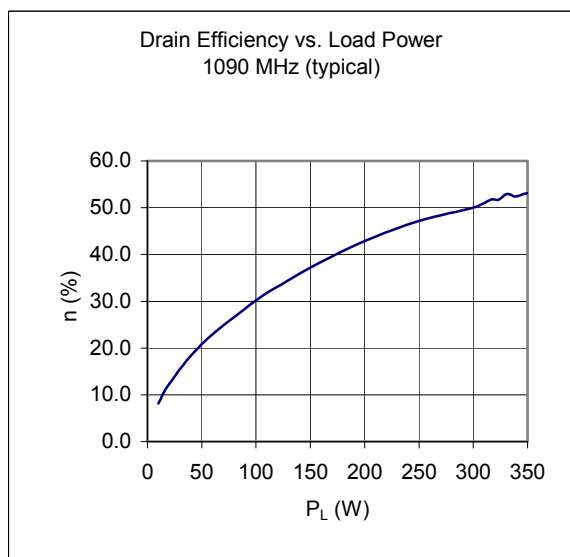
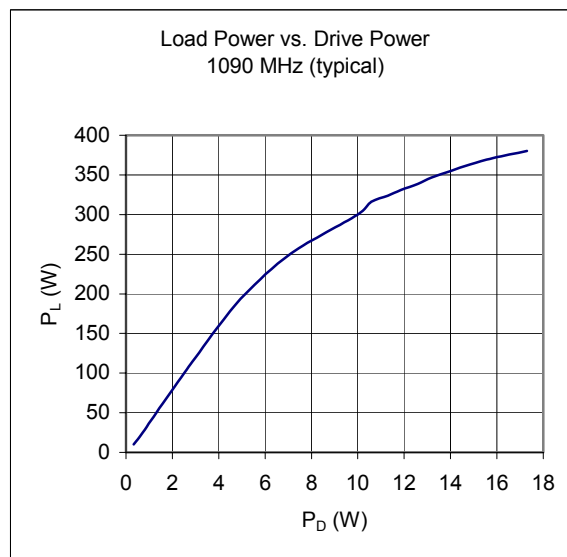
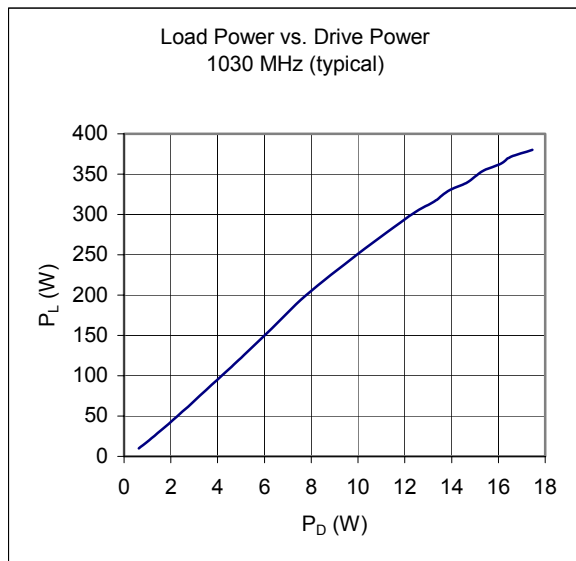
| | | | | | | |
|-----------------|--------------------------|--|----|----|-----|----|
| G _{PS} | Common Source Power Gain | Pulse width = 32 μs, LTDC=2% | 13 | 14 | | dB |
| P _d | Pulse Droop | F=1030/1090 MHz, P _{out} = 300W | | | 0.5 | dB |
| η _d | Drain Efficiency | F = 1030 MHz, P _{out} = 300W | 43 | | | % |
| ψ | Load Mismatch | F = 1090 MHz, P _{out} = 300W | | | 3:1 | |

NOTES: 1. At rated output power and pulse conditions

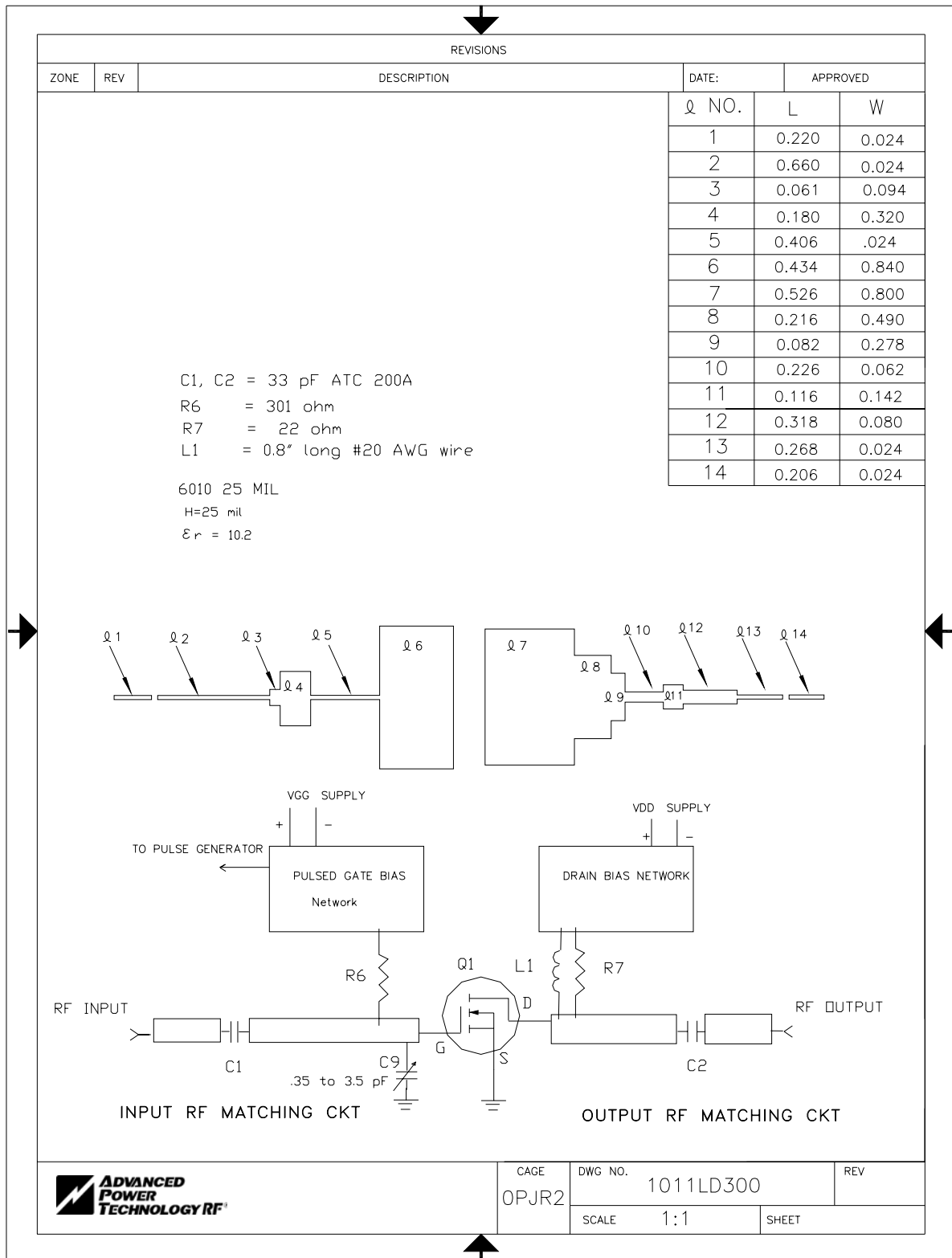
2. Pulse Format 1: 32μs, 2% Long Term Duty Factor

Rev. B – Apr 2004

Advanced Power Technology reserves the right to change, without notice, the specifications and information contained herein. Visit our web site at www.advancedpower.com or contact our factory direct.



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